Dual Precision Retriggerable/Resettable Monostable Multivibrator

The MC14538B is a dual, retriggerable, resettable monostable multivibrator. It may be triggered from either edge of an input pulse, and produces an accurate output pulse over a wide range of widths, the duration and accuracy of which are determined by the external timing components, C_X and R_X . Output Pulse Width $T = R_X \cdot C_X$ (secs)

$$R_X = \Omega$$

 $C_X = Farads$

- Features
- Unlimited Rise and Fall Time Allowed on the A Trigger Input
- Pulse Width Range = $10 \ \mu s$ to $10 \ s$
- Latched Trigger Inputs
- Separate Latched Reset Inputs
- 3.0 Vdc to 18 Vdc Operational Limits
- Triggerable from Positive (A Input) or Negative–Going Edge (B–Input)
- Capable of Driving Two Low–Power TTL Loads or One Low–Power Schottky TTL Load Over the Rated Temperature Range
- Pin-for-pin Compatible with MC14528B and CD4528B (CD4098)
- $\bullet\,$ Use the MC54/74HC4538A for Pulse Widths Less Than 10 μs with Supplies Up to 6 V
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (Voltages Referenced to V_{SS})

(3						
Symbol	Parameter	Value	Unit			
V _{DD}	DC Supply Voltage Range	-0.5 to +18.0	V			
V _{in} , V _{out}	Input or Output Voltage Range (DC or Transient)	–0.5 to V _{DD} + 0.5	V			
I _{in} , I _{out}	Input or Output Current (DC or Transient) per Pin	±10	mA			
P _D	Power Dissipation, per Package (Note 1)	500	mW			
T _A	Operating Temperature Range	-55 to +125	°C			
T _{stg}	Storage Temperature Range	-65 to +150	°C			
ΤL	Lead Temperature (8-Second Soldering)	260	°C			

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Temperature Derating:

Plastic "P and D/DW" Packages: - 7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}.$

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.



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MARKING DIAGRAMS 16<u> በሰላ ሰለ ሰለ ሰ</u> PDIP-16 MC14538BCP **P SUFFIX** O AWLYYWWG **CASE 648** ϯʹϼϘϘϘϘϘϤ 16 <u>iănnnnnn</u> SOIC-16 14538BG **D SUFFIX** AWLYWW 0 CASE 751B SOIC-16WB 14538BG DW SUFFIX AWLYYWW CASE 751G 1 1 1 1 1 1 1 1 1 1 1 1 16 AAAAAAAA 14 TSSOP-16 538B DT SUFFIX ALYW-CASE 948F 1 8 8 8 8 8 8 8 8 8 16 . . SOEIAJ-16 MC14538B F SUFFIX ALYWG **CASE 966** 0 ŬDDDDDDD = Assembly Location Α WL, L = Wafer Lot YY. Y = Year WW.W = Work Week = Pb-Free Indicator G or •

(Note: Microdot may be in either location)

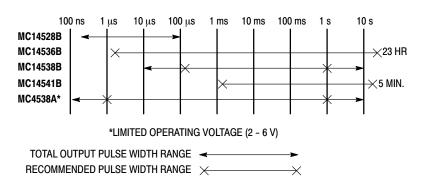
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

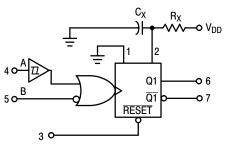
PIN ASSIGNMENT

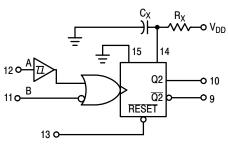
r			
v _{ss} [1●	16] V _{DD}
C _X /R _X A	2	15] V _{SS}
RESET A [3	14] C _X /R _X B
A _A [4	13	RESET B
B _A [5	12	A _B
Q _A [6	11	B _B
\overline{Q}_{A}	7	10] Q _B
v _{ss} [8	9]

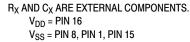
ONE-SHOT SELECTION GUIDE











ORDERING INFORMATION

Device	Package	Shipping [†]		
MC14538BCPG	PDIP-16 (Pb-Free)	500 Units / Rail		
MC14538BDG	SOIC-16			
NLV14538BDG*	(Pb-Free)	48 Units / Rail		
MC14538BDR2G	SOIC-16	0500 Linita / Tana & Daal		
NLV14538BDR2G*	(Pb-Free)	2500 Units / Tape & Reel		
MC14538BDTR2G	TSSOP-16			
NLV14538BDTR2G*	(Pb-Free)	2500 Units / Tape & Reel		
MC14538BDWG	SOIC-16 WB	47 Unite / Deil		
NLV14538BDWG*	(Pb-Free)	47 Units / Rail		
MC14538BDWR2G	SOIC-16 WB	1000 Unite / Tapa & Baal		
NLV14538BDWR2G*	(Pb-Free)	1000 Units / Tape & Reel		
MC14538BFG	SOEIAJ-16 (Pb-Free)	50 Units / Rail		
MC14538BFELG	SOEIAJ-16 (Pb-Free)	2000 Units / Tape & Reel		

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

		V	- 5	5°C		25°C		125°C		
Characteristic	Symbol	V _{DD} Vdc	Min	n Max	x Min	Typ (Note 2)	Max	Min	Мах	Unit
Output Voltage "0" Leve $V_{in} = V_{DD}$ or 0	V _{OL}	5.0 10 15	- - -	0.05 0.05 0.05	- - -	0 0 0	0.05 0.05 0.05	- - -	0.05 0.05 0.05	Vdc
"1" Leve $V_{in} = 0 \text{ or } V_{DD}$	V _{OH}	5.0 10 15	4.95 9.95 14.95	- - -	4.95 9.95 14.95	5.0 10 15	- - -	4.95 9.95 14.95	- - -	Vdc
$\label{eq:VO} \begin{array}{ll} \mbox{Input Voltage} & \mbox{``0" Leve} \\ \mbox{(V}_{O} = 4.5 \mbox{ or } 0.5 \mbox{ Vdc}) \\ \mbox{(V}_{O} = 9.0 \mbox{ or } 1.0 \mbox{ Vdc}) \\ \mbox{(V}_{O} = 13.5 \mbox{ or } 1.5 \mbox{ Vdc}) \end{array}$	V _{IL}	5.0 10 15	_ _ _	1.5 3.0 4.0	_ _ _	2.25 4.50 6.75	1.5 3.0 4.0	_ _ _	1.5 3.0 4.0	Vdc
"1" Leve (V _O = 0.5 or 4.5 Vdc) (V _O = 1.0 or 9.0 Vdc) (V _O = 1.5 or 13.5 Vdc)	V _{IH}	5.0 10 15	3.5 7.0 11		3.5 7.0 11	2.75 5.50 8.25	- - -	3.5 7.0 11	_ _ _	Vdc
$\begin{array}{l} \text{Output Drive Current} \\ (V_{OH} = 2.5 \ \text{Vdc}) \\ (V_{OH} = 4.6 \ \text{Vdc}) \\ (V_{OH} = 9.5 \ \text{Vdc}) \\ (V_{OH} = 13.5 \ \text{Vdc}) \end{array}$	Іон	5.0 5.0 10 15	- 3.0 - 0.64 - 1.6 - 4.2		- 2.4 - 0.51 - 1.3 - 3.4	- 4.2 - 0.88 - 2.25 - 8.8		- 1.7 - 0.36 - 0.9 - 2.4		mAdc
	I _{OL}	5.0 10 15	0.64 1.6 4.2		0.51 1.3 3.4	0.88 2.25 8.8	_ _ _	0.36 0.9 2.4		mAdc
Input Current, Pin 2 or 14	l _{in}	15	-	±0.05	-	±0.00001	±0.05	-	±0.5	μAdc
Input Current, Other Inputs	l _{in}	15	-	±0.1	-	±0.00001	±0.1	-	±1.0	μAdc
Input Capacitance, Pin 2 or 14	C _{in}	-	-	-	-	25	-	-	-	pF
Input Capacitance, Other Inputs (V _{in} = 0)	C _{in}	-	-	-	-	5.0	7.5	-	-	pF
Quiescent Current (Per Package) $Q = Low, \overline{Q} = High$	I _{DD}	5.0 10 15	- - -	5.0 10 20		0.005 0.010 0.015	5.0 10 20	- - -	150 300 600	μAdc
Quiescent Current, Active State (Both) (Per Package) $Q = High, \overline{Q} = Low$	I _{DD}	5.0 10 15	- - -	2.0 2.0 2.0		0.04 0.08 0.13	0.20 0.45 0.70	- - -	2.0 2.0 2.0	mAdc
Total Supply Current at an external load capacitance (C_L) and at external timing network (R_X , C_X) (Note 3)	ΙŢ	5.0 10		I _T = (8.0 x I _T = (1.25 where:	k 10 ^{–2}) R x 10 ^{–1}) Ι I _T in μΑ (α C _X in μF,	$(C_Xf + 4C_Xf - X_C_Xf + 9C_Xf + 9C_Xf + 12C_Xf + 12C_X$	+ 2 x 10 ⁻⁵ xf + 3 x 10 ble switch in k ohms	$\overline{^{5} C_{L}^{f}}$ 0 ⁻⁵ C _L f ning only),		μAdc

Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
 The formulas given are for the typical characteristics only at 25°C.

SWITCHING CHARACTERISTICS (Note 4) (CL = 50 pF, TA = 25 $^{\circ}$ C)

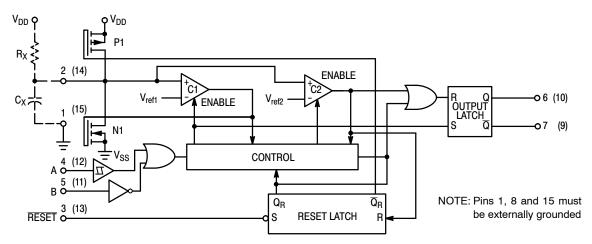
		v				
Characteristic	Symbol	V _{DD} Vdc	Min	Typ (Note 5)	Max	Unit
Output Rise Time	t _{TLH}					ns
t _{TLH} = (1.35 ns/pF) C _L + 33 ns		5.0	-	100	200	
t _{TLH} = (0.60 ns/pF) C _L + 20 ns		10	-	50	100	
t _{TLH} = (0.40 ns/pF) C _L + 20 ns		15	-	40	80	
Output Fall Time	t _{THL}					ns
t _{THL} = (1.35 ns/pF) C _L + 33 ns		5.0	-	100	200	
$t_{THL} = (0.60 \text{ ns/pF}) C_L + 20 \text{ ns}$		10	-	50	100	
t _{THL} = (0.40 ns/pF) C _L + 20 ns		15	-	40	80	
Propagation Delay Time	t _{PLH} ,					ns
A or B to Q or \overline{Q}	t _{PHL}					
t_{PLH} , $t_{PHL} = (0.90 \text{ ns/pF}) C_L + 255 \text{ ns}$		5.0	-	300	600	
t_{PLH} , $t_{PHL} = (0.36 \text{ ns/pF}) \text{ C}_{L} + 132 \text{ ns}$		10	-	150	300	
t_{PLH} , t_{PHL} = (0.26 ns/pF) C _L + 87 ns		15	-	100	220	
Reset to Q or \overline{Q}						ns
t_{PLH} , t_{PHL} = (0.90 ns/pF) C _L + 205 ns		5.0	-	250	500	
t_{PLH} , t_{PHL} = (0.36 ns/pF) C _L + 107 ns		10	-	125	250	
t_{PLH} , t_{PHL} = (0.26 ns/pF) C _L + 82 ns		15	-	95	190	
Input Rise and Fall Times	t _r , t _f	5	-	-	15	μs
Reset		10	-	-	5	
		15	-	-	4	
B Input		5	-	300	1.0	ms
1		10	-	1.2	0.1	
		15	-	0.4	0.05	
A Input		5		1		-
		10		No Limit		
		15				
Input Pulse Width	t _{WH} ,	5.0	170	85	-	ns
, A, B, or Reset	twL	10	90	45	_	
		15	80	40	-	
Retrigger Time	t _{rr}	5.0	0	_	_	ns
		10	0	_	_	
		15	0	-	-	
Output Pulse Width — Q or Q	Т					μs
Refer to Figures 8 and 9						
$C_X = 0.002 \ \mu F, \ R_X = 100 \ k\Omega$		5.0	198	210	230	
		10	200	212	232	
		15	202	214	234	
$C_X = 0.1 \ \mu F, R_X = 100 \ k\Omega$		5.0	9.3	9.86	10.5	ms
		10	9.4	10	10.6	
		15	9.5	10.14	10.7	
$C_X = 10 \ \mu\text{F}, \ \text{R}_X = 100 \ \text{k}\Omega$		5.0	0.91	0.965	1.03	s
		10	0.92	0.98	1.04	
		15	0.93	0.99	1.06	1
Pulse Width Match between circuits in	100	5.0	-	± 1.0	± 5.0	%
the same package.	$[(T_1 - T_2)/T_1]$	10	-	± 1.0	± 5.0	
$C_X = 0.1 \ \mu\text{F}, R_X = 100 \ \text{k}\Omega$		15	1	± 1.0	± 5.0	1

The formulas given are for the typical characteristics only at 25°C.
 Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

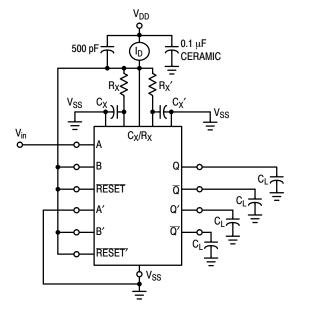
OPERATING CONDITIONS

External Timing Resistance	R _X	-	5.0	-	(Note 6)	kΩ
External Timing Capacitance	C _X	-	0	-	No Limit (Note 7)	μF

6. The maximum usable resistance R_X is a function of the leakage of the capacitor C_X, leakage of the MC14538B, and leakage due to board layout and surface resistance. Susceptibility to externally induced noise signals may occur for R_X > 1 MΩ.
7. If C_X > 15 µF, use discharge protection diode per Fig. 11.







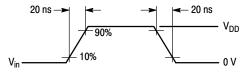


Figure 2. Power Dissipation Test Circuit and Waveforms

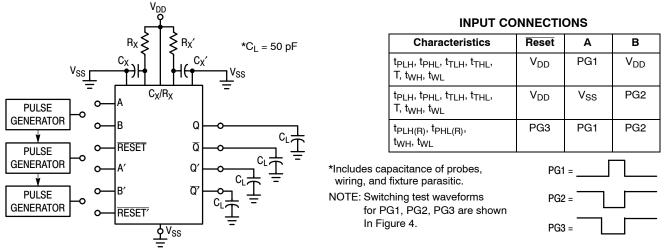


Figure 3. Switching Test Circuit

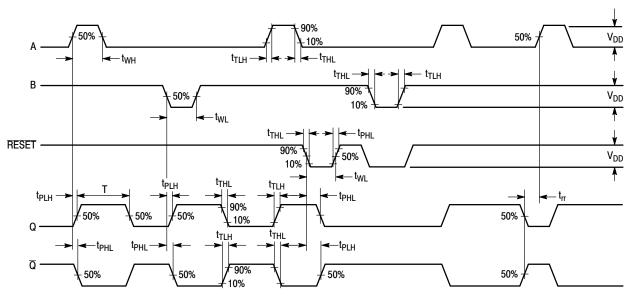
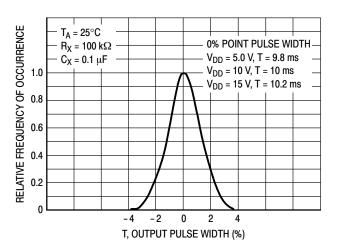


Figure 4. Switching Test Waveforms





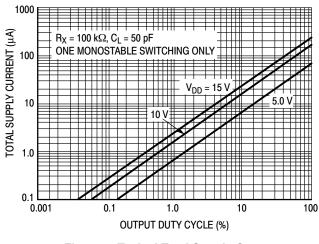


Figure 7. Typical Total Supply Current versus Output Duty Cycle

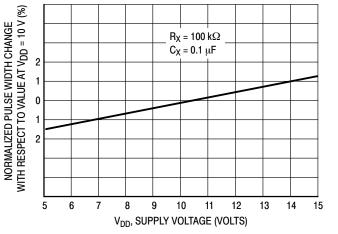
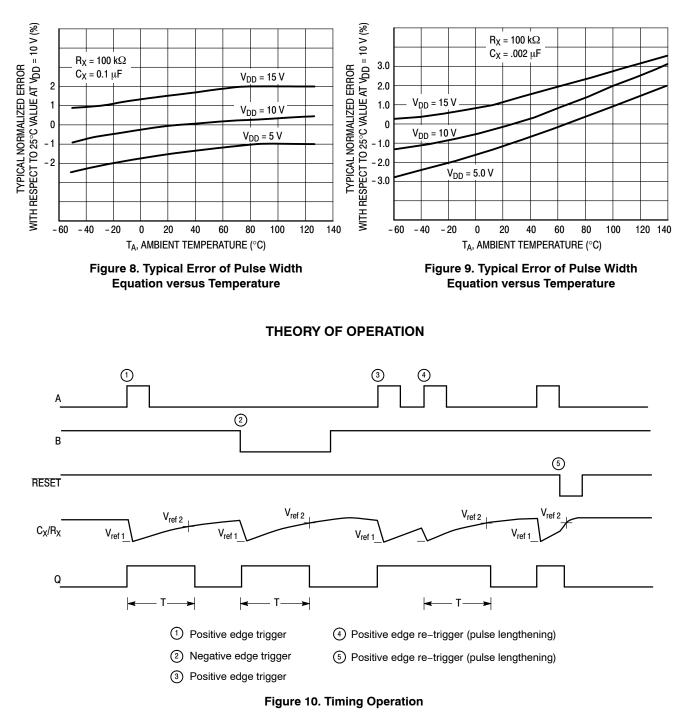


Figure 6. Typical Pulse Width Variation as a Function of Supply Voltage V_{DD}

FUNCTION TABLE

	Inputs	Outputs		
Reset	Α	В	Q	Q
H	ے۔	H	Г.	디디
H	۲	∼	Г	
H	ノ へ	L	Not Triggered	
H	H	上	Not Triggered	
H	L, H, ~-	H	Not Triggered	
	L	L, H, <i>-</i> /	Not Triggered	
L	X	X	L	H
て ノ	X	X	Not Tri	ggered



TRIGGER OPERATION

The block diagram of the MC14538B is shown in Figure 1, with circuit operation following.

As shown in Figure 1 and 10, before an input trigger occurs, the monostable is in the quiescent state with the Q output low, and the timing capacitor CX completely charged to V_{DD} . When the trigger input A goes from V_{SS} to V_{DD} (while inputs B and Reset are held to V_{DD}) a valid trigger is recognized, which turns on comparator C1 and N-channel transistor N1 1. At the same time the output latch is set. With transistor N1 on, the capacitor CX rapidly discharges toward V_{SS} until V_{ref1} is reached. At this point the output of comparator C1 changes state and transistor N1 turns off. Comparator C1 then turns off while at the same time comparator C2 turns on. With transistor N1 off, the capacitor C_X begins to charge through the timing resistor, R_X , toward V_{DD} . When the voltage across C_X equals $V_{ref 2}$, comparator C2 changes state, causing the output latch to reset (Q goes low) while at the same time disabling comparator C2 2. This ends at the timing cycle with the monostable in the quiescent state, waiting for the next trigger.

In the quiescent state, C_X is fully charged to V_{DD} causing the current through resistor R_X to be zero. Both comparators are "off" with total device current due only to reverse junction leakages. An added feature of the MC14538B is that the output latch is set via the input trigger without regard to the capacitor voltage. Thus, propagation delay from trigger to Q is independent of the value of C_X , R_X , or the duty cycle of the input waveform.

RETRIGGER OPERATION

The MC14538B is retriggered if a valid trigger occurs ⁽³⁾ followed by another valid trigger ⁽⁴⁾ before the Q output has returned to the quiescent (zero) state. Any retrigger, after the timing node voltage at pin 2 or 14 has begun to rise from $V_{ref 1}$, but has not yet reached $V_{ref 2}$, will cause an increase in output pulse width T. When a valid retrigger is initiated ⁽⁴⁾, the voltage at C_X/R_X will again drop to $V_{ref 1}$ before progressing along the RC charging curve toward V_{DD} . The Q output will remain high until time T, after the last valid retrigger.

RESET OPERATION

The MC14538B may be reset during the generation of the output pulse. In the reset mode of operation, an input pulse

on Reset sets the reset latch and causes the capacitor to be fast charged to V_{DD} by turning on transistor P1 (5). When the voltage on the capacitor reaches $V_{ref 2}$, the reset latch will clear, and will then be ready to accept another pulse. It the Reset input is held low, any trigger inputs that occur will be inhibited and the Q and \overline{Q} outputs of the output latch will not change. Since the Q output is reset when an input low level is detected on the Reset input, the output pulse T can be made significantly shorter than the minimum pulse width specification.

POWER-DOWN CONSIDERATIONS

Large capacitance values can cause problems due to the large amount of energy stored. When a system containing the MC14538B is powered down, the capacitor voltage may discharge from V_{DD} through the standard protection diodes at pin 2 or 14. Current through the protection diodes should be limited to 10 mA and therefore the discharge time of the V_{DD} supply must not be faster than (V_{DD}) . (C)/(10 mA). For example, if $V_{DD} = 10$ V and $C_X = 10 \,\mu\text{F}$, the V_{DD} supply should discharge no faster than $(10 \text{ V}) \times (10 \,\mu\text{F})/(10 \text{ mA}) = 10$ ms. This is normally not a problem since power supplies are heavily filtered and cannot discharge at this rate.

When a more rapid decrease of V_{DD} to zero volts occurs, the MC14538B can sustain damage. To avoid this possibility use an external clamping diode, D_X , connected as shown in Fig. 11.

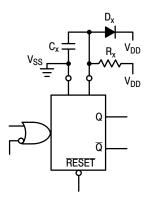
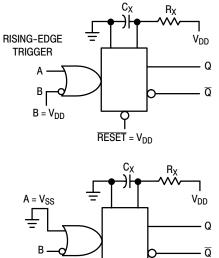
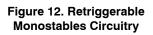


Figure 11. Use of a Diode to Limit Power Down Current Surge

TYPICAL APPLICATIONS







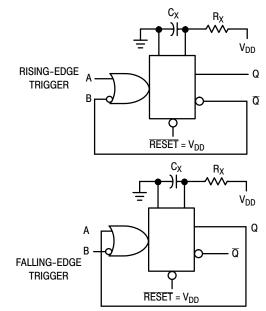


Figure 13. Non–Retriggerable Monostables Circuitry

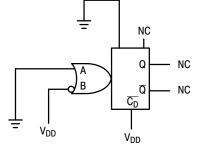
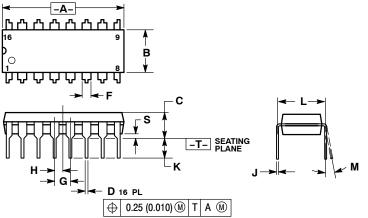


Figure 14. Connection of Unused Sections

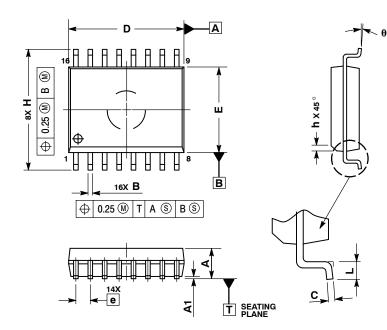
PDIP-16 P SUFFIX CASE 648-08 ISSUE T



- NOTES:
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 ROUNDED CORNERS OPTIONAL.

	INCHES		MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
К	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
М	0 °	10 °	0 °	10 °	
S	0.020	0.040	0.51	1.01	

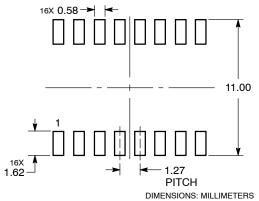
SOIC-16 WB CASE 751G-03 ISSUE D



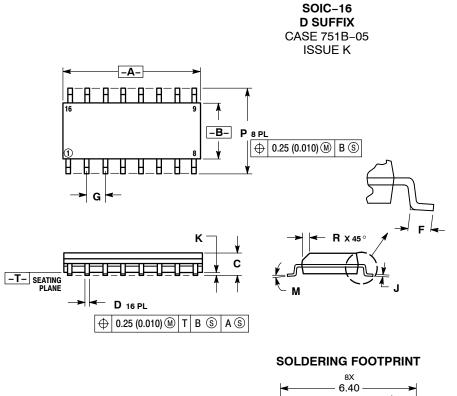
- NOTES:
 DIMENSIONS ARE IN MILLIMETERS.
 INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
 DIMENSIONS D AND E DO NOT INLCUDE MOLD PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
 DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

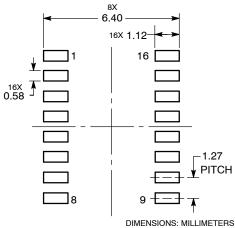
	MILLIMETERS				
DIM	MIN	MAX			
Α	2.35	2.65			
A1	0.10	0.25			
в	0.35	0.49			
С	0.23	0.32			
D	10.15	10.45			
Е	7.40	7.60			
e	1.27	BSC			
Н	10.05	10.55			
h	0.25	0.75			
L	0.50	0.90			
q	0 °	7 °			

SOLDERING FOOTPRINT



PACKAGE DIMENSIONS

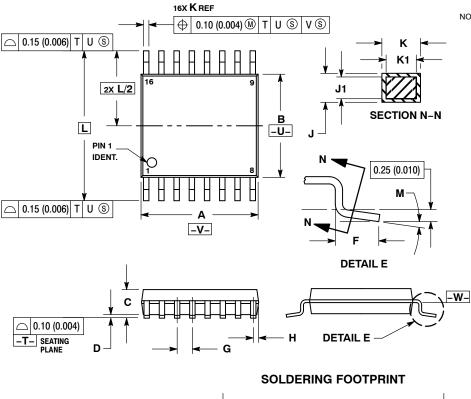




NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER. 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION. 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE. 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	9.80	10.00	0.386	0.393	
В	3.80	4.00	0.150	0.157	
C	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050 BSC		
J	0.19	0.25	0.008	0.009	
K	0.10	0.25	0.004	0.009	
М	0 °	7°	0 °	7°	
Р	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	





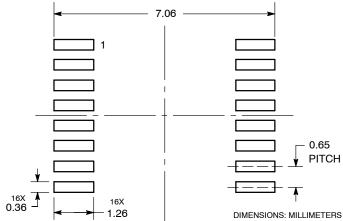
NOTES:

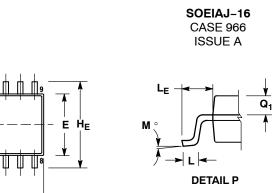
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
 DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.

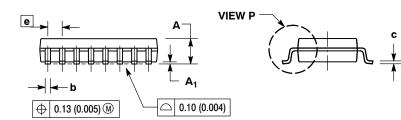
CONDITION. 6. TERMINAL NUMBERS ARE SHOWN FOR

TERMINENCE ONLY.
 DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	4.90	5.10	0.193	0.200	
В	4.30	4.50	0.169	0.177	
С		1.20		0.047	
D	0.05	0.15	0.002	0.006	
F	0.50	0.75	0.020	0.030	
G	0.65	BSC	0.026 BSC		
Н	0.18	0.28	0.007	0.011	
ſ	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
κ	0.19	0.30	0.007	0.012	
K1	0.19	0.25	0.007	0.010	
L	6.40 BSC		0.252 BSC		
М	0 °	8°	0 °	8°	







D

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER. 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0 000) DEP SIDE
- (0.006) PER SIDE. 4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- THE FERENCE UNIT. 5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

MILLIMETERS		INC	HES	
MIN	MAX	MIN	MAX	
	2.05		0.081	
0.05	0.20	0.002	0.008	
0.35	0.50	0.014	0.020	
0.10	0.20	0.007	0.011	
9.90	10.50	0.390	0.413	
5.10	5.45	0.201	0.215	
1.27	BSC	0.050 BSC		
7.40	8.20	0.291	0.323	
0.50	0.85	0.020	0.033	
1.10	1.50	0.043	0.059	
0 °	10 °	0 °	10 °	
0.70	0.90	0.028	0.035	
	0.78		0.031	
	MIN 0.05 0.35 0.10 9.90 5.10 1.27 7.40 0.50 1.10 0.°	MIN MAX 2.05 0.05 0.20 0.35 0.50 0.10 0.20 9.90 10.50 5.10 5.45 1.27 BSC 7.40 7.40 8.20 0.50 0.85 1.10 1.50 0 ° 10 ° 0.70 0.70 0.90	MIN MAX MIN 2.05 0.05 0.20 0.002 0.35 0.50 0.014 0.10 0.20 0.007 9.90 10.50 0.390 5.10 5.45 0.201 1.27 BSC 0.050 7.40 8.20 0.291 0.50 0.85 0.020 1.10 1.50 0.043 0~0 10~0 0~0 0~70 0.90 0.028	

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